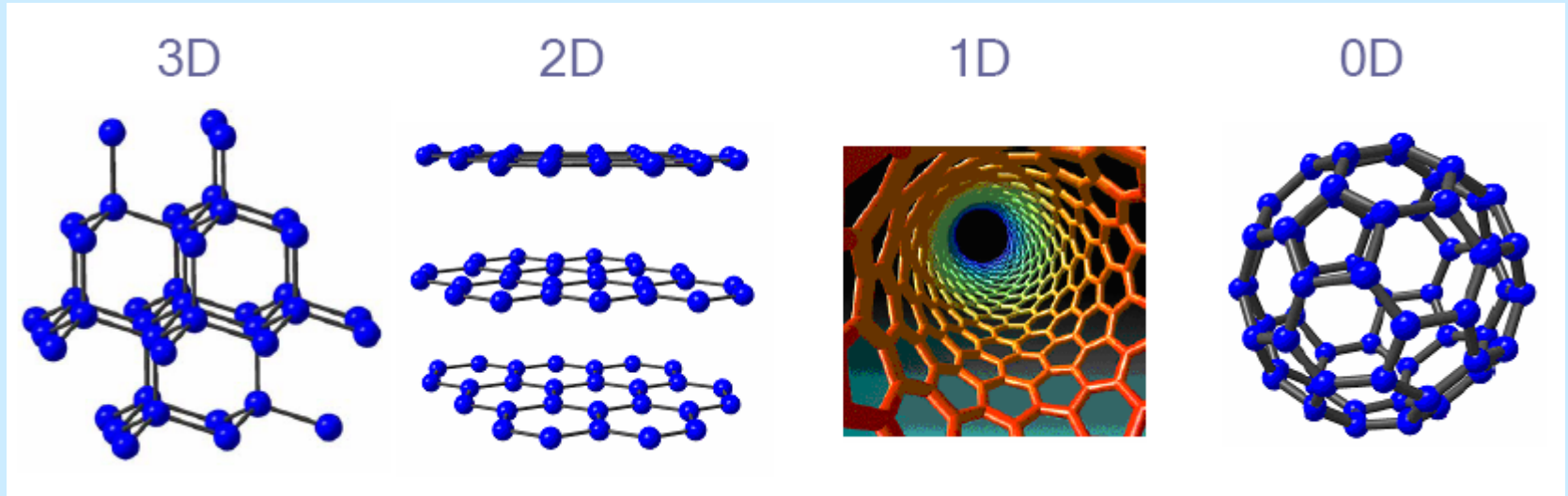


Dimension-Properties Interplay



Brilliant, Transparent
Mohs Hardness 10
20 W/cmK
High Melting point

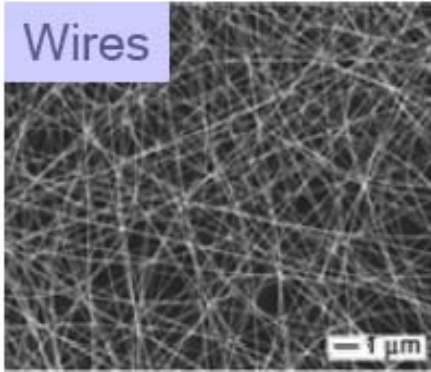
Metallic lusture Opaque
1-2
25
Lubricant

Black, Fibrous
1-1.2
6000
Unusual
Electrical Behaviour

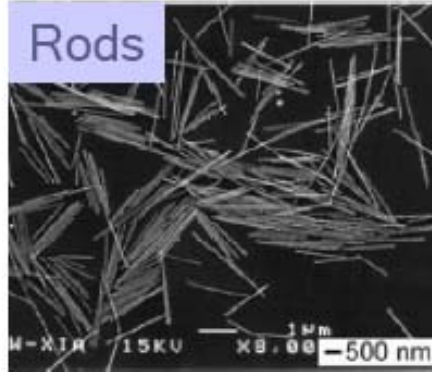
Black Shiny Crystals
-
-
Superconductor
(10-40 K)

High Axial Ratio Nanostructures

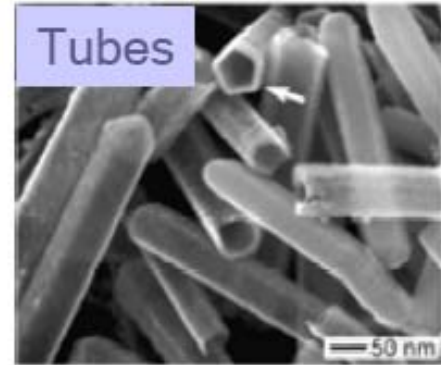
Wires



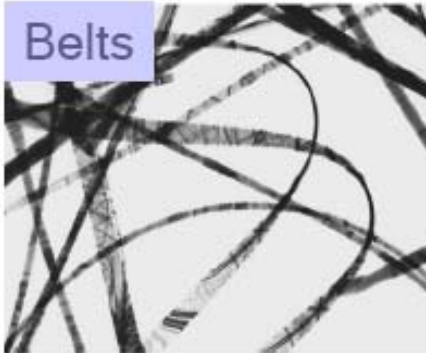
Rods



Tubes

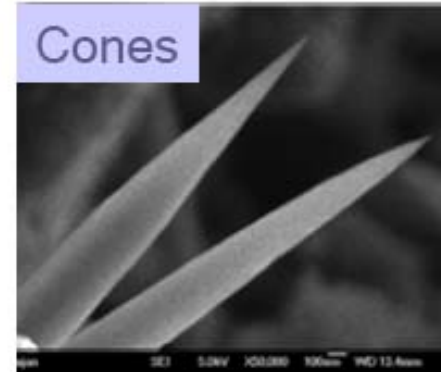


Belts



One Dimensional
Architectures

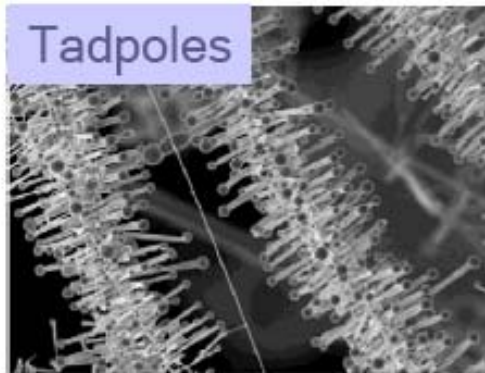
Cones



Brushes



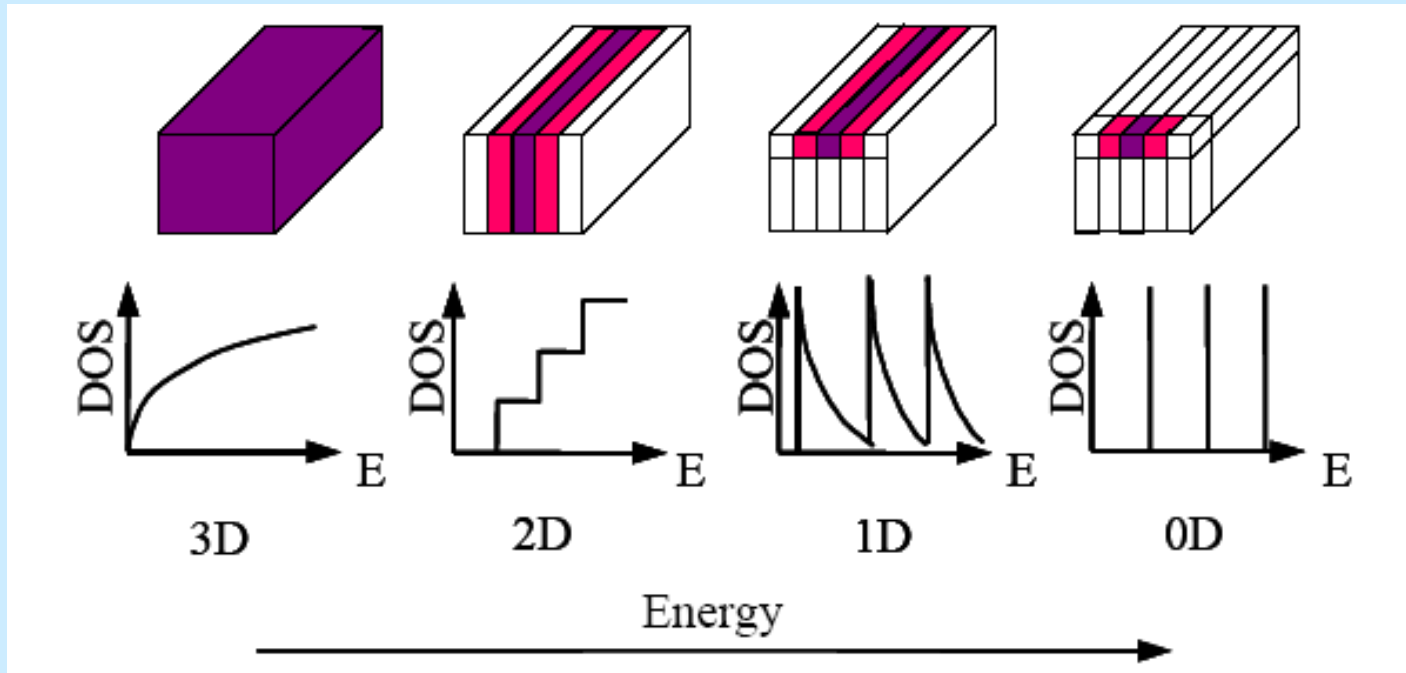
Tadpoles



Flowers



Role of Dimensionality



Role of Dimensionality

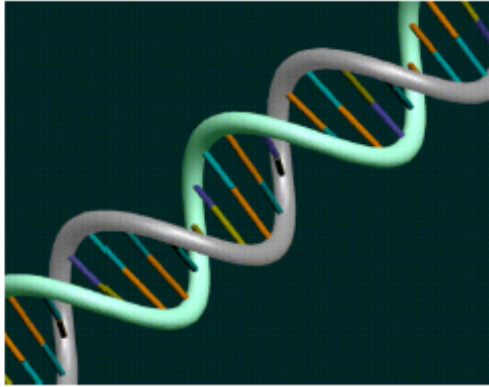
$$3 \text{ D: } E = \frac{\hbar^2}{2m} [k_x^2 + k_y^2 + k_z^2]$$

$$2 \text{ D: } E = \frac{\hbar^2}{2m} \left[k_x^2 + k_y^2 + \left(n_z \frac{\pi}{L} \right)^2 \right] \quad n_z = 1, 2, 3 \dots$$

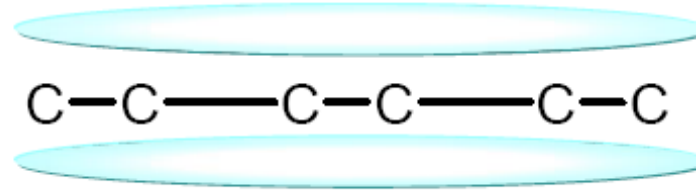
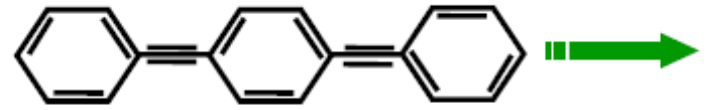
$$1 \text{ D: } E = \frac{\hbar^2}{2m} \left[k_x^2 + \left(n_y \frac{\pi}{L} \right)^2 + \left(n_z \frac{\pi}{L} \right)^2 \right] \quad n_y, n_z = 1, 2, 3 \dots$$

$$0 \text{ D: } E = \frac{\hbar^2}{2m} \left[\left(n_x \frac{\pi}{L} \right)^2 + \left(n_y \frac{\pi}{L} \right)^2 + \left(n_z \frac{\pi}{L} \right)^2 \right] \quad n_x, n_y, n_z = 1, 2, 3 \dots$$

1D Nanostructures

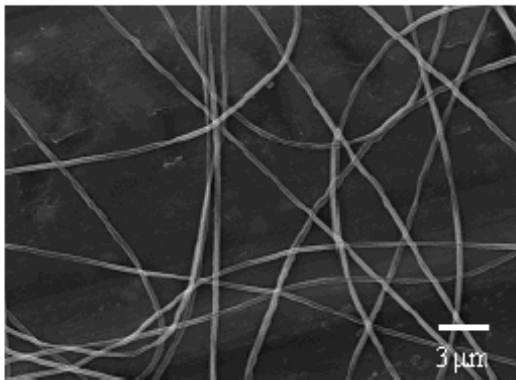


DNA

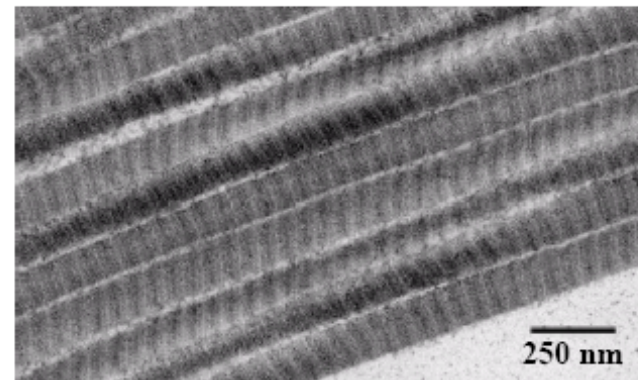


Molecular Wire

The Nano World



Poly (ethylene oxide)



Collagen Fibrils

Characteristics of 1D Nanostructures

Properties

Small

Light weight

Novel 1-D properties

High aspect ratio

High surface area

Potential applications

Interconnects

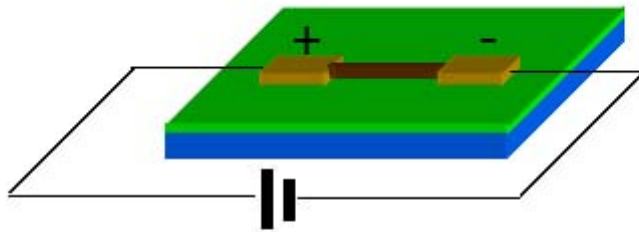
Novel Probes

Multifunctional

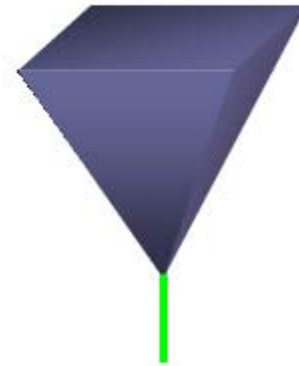
Hierarchical alignment

Building blocks for devices

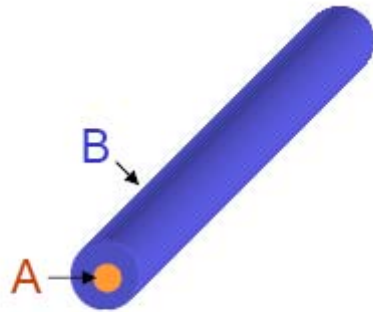
Potential of Nanowires



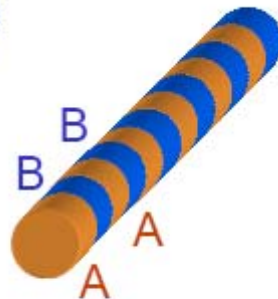
Electron Transport
'Nano-cables'



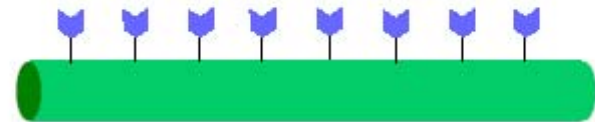
AFM & STM Tips



Core-shell

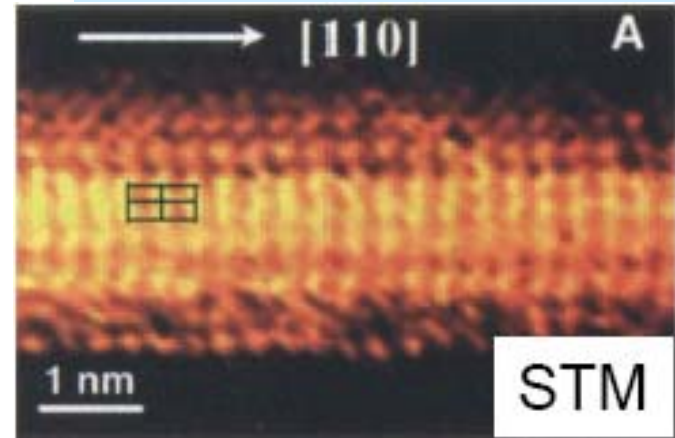
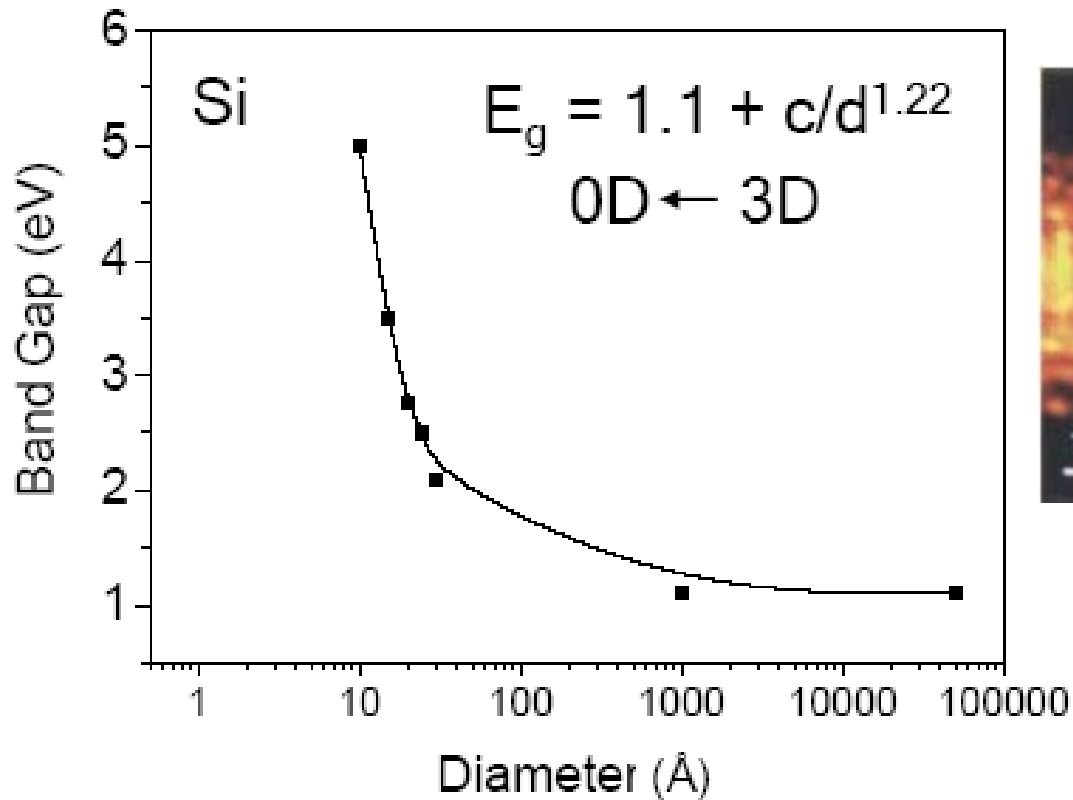


Superlattice



Surface Modification

Effect of Confinement

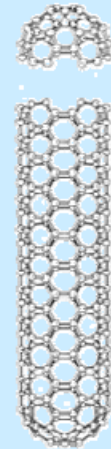


The band gap increases with decreasing diameter (quantum confinement)

Carbon Nanotubes



- Discovered by Iijima (1991, NEC)
- Rolled up sheet of graphene
- Capped at the ends with half a fullerene



Carbon Nanotubes

Single Walled Nanotube (SWNT)

- Single atomic layer wall
- Diameter of 1 – 5 nm
- Length several microns

Multi Walled Nanotube (MWNT)

- Concentric tubes ca. 50 in number
- Inner diameters : 1.5 – 15 nm
- Outer diameters : 2.5 – 30 nm

CNTs: Properties and Potential

Electronic: Bandgap $E_g \sim 1/d$

Magnetic: Anisotropic magn. susceptibility $\chi_{\perp} \gg \chi_{\parallel}$

Mechanical: Young's Modulus

~ 1 TPa (SWNT)

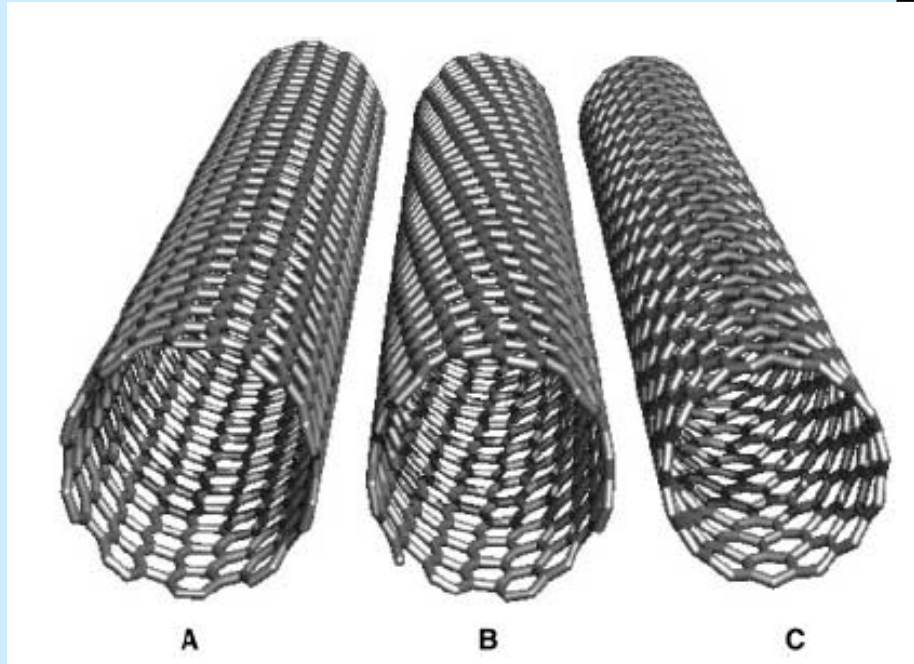
1.25 TPa (MWNT)

(Steel: 230 GPa)

Thermal: Conductivity 6000 W/m.K

(Copper 400 W/m.K)

Defect-free (n,m) SWNTs with open ends



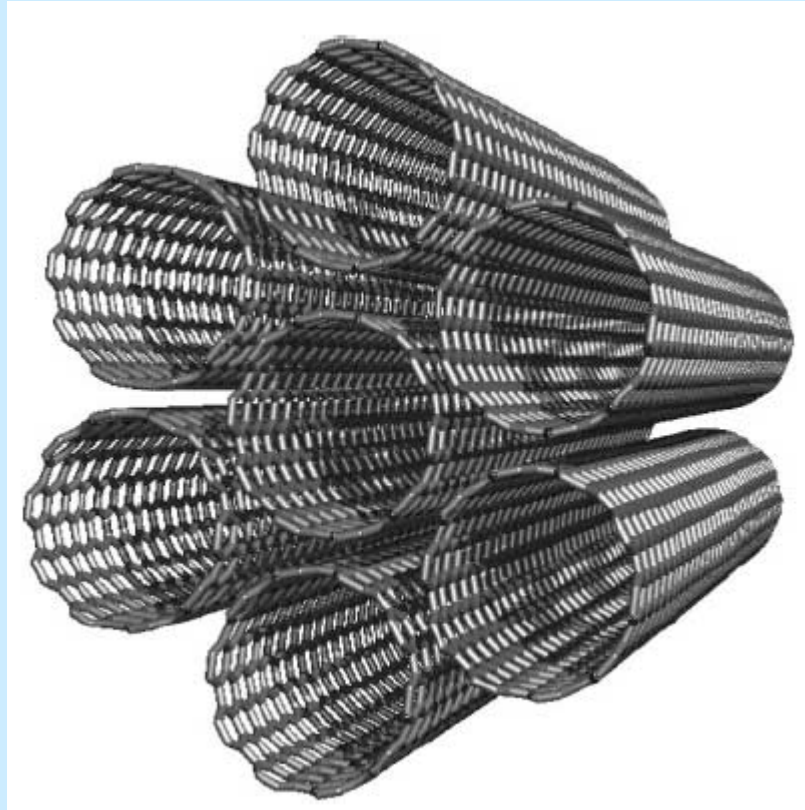
A) A metallic conducting (10,10) tube (armchair)

B) a chiral, semiconducting (12,7) tube,

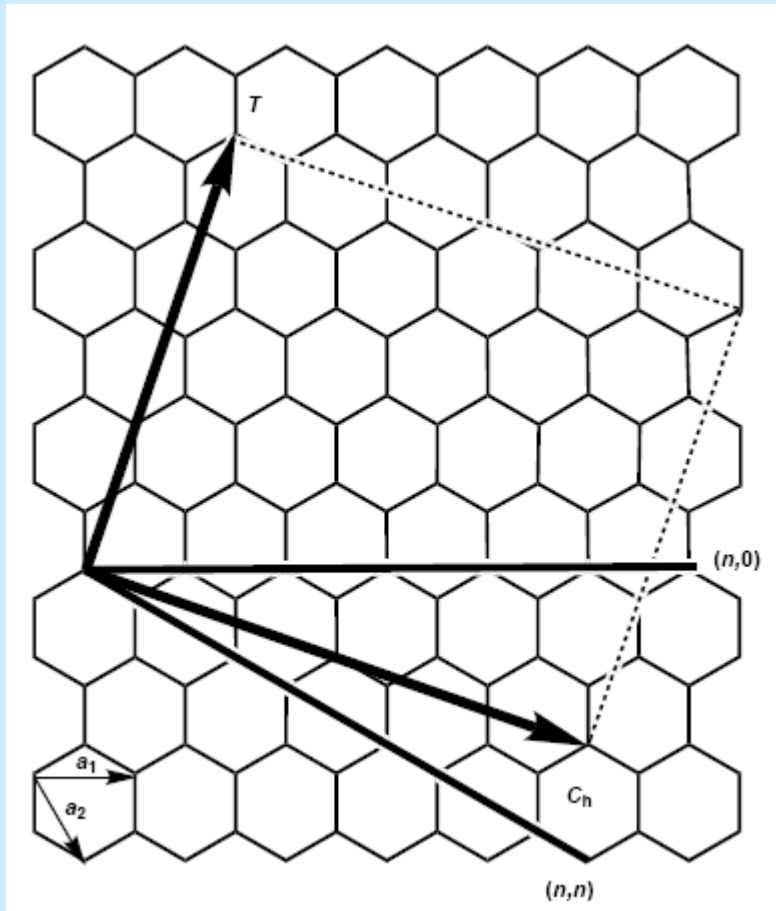
C) a conducting (15,0) tube (zigzag).

The armchair (A) and zigzag (C) tubes are achiral.

All the (n,n) armchair tubes are metallic, whilst this is only the case with chiral or zigzag tubes if $(n-m)/3$ is a whole number, otherwise, they are semiconductors



A bundle of (10,10) nanotubes held together with strong π - π -stacking interactions

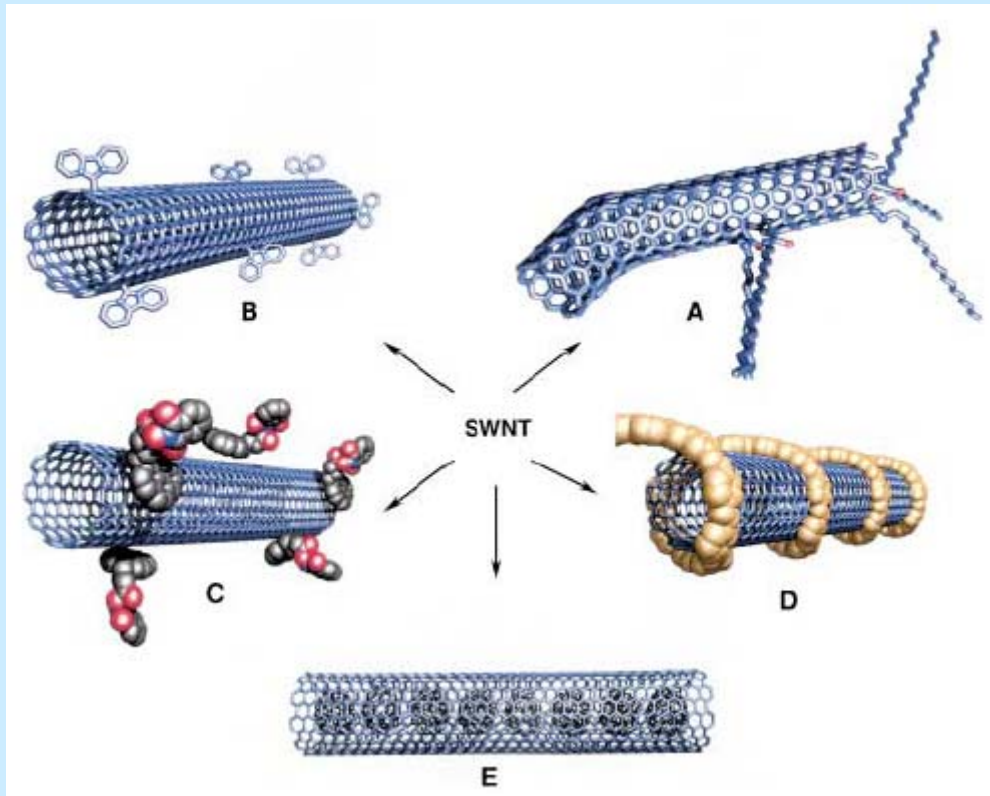


a 2D graphite layer
 the lattice vectors a_1 and a_2
 the roll-up vector $C_h = na_1 + ma_2$
 Achiral tubes exhibit roll-up vectors
 derived from $(n,0)$ (zigzag) or (n,n)
 (armchair).

The translation vector T is parallel
 to the tube axis and defines the 1D
 unit cell.

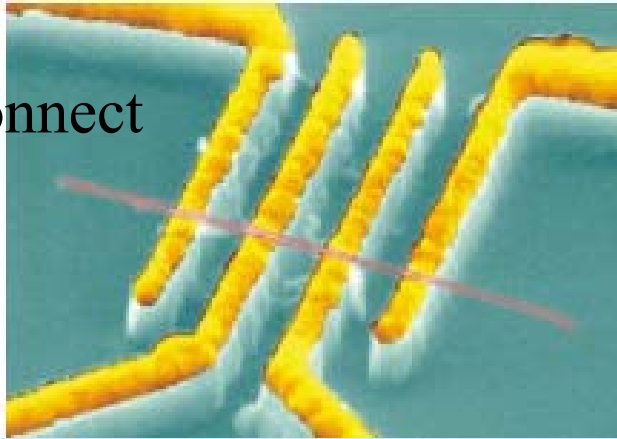
The rectangle represents an unrolled
 unit cell, defined by T and C_h
 In this example, $(n,m) = (4,2)$

Functionalization possibilities for SWNTs

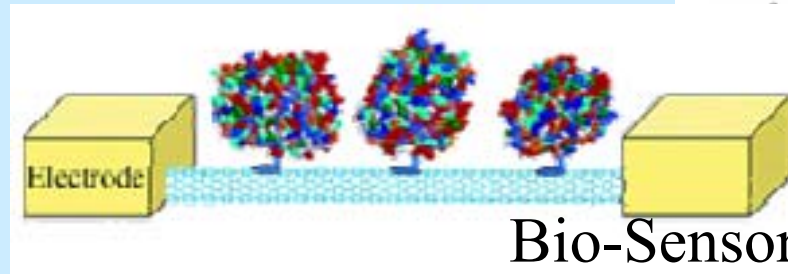
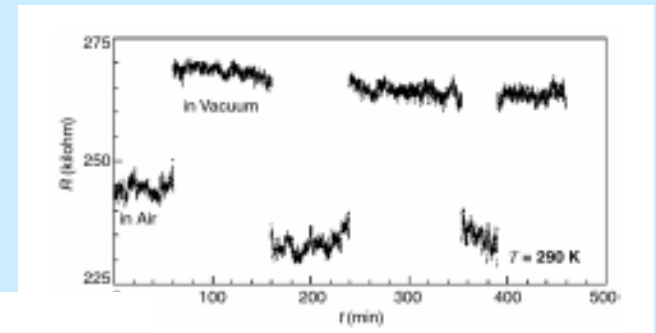
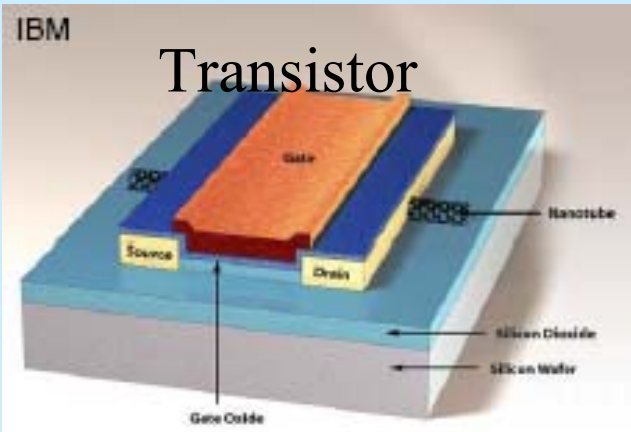


- A) defect-group functionalization
- B) covalent sidewall functionalization
- C) noncovalent exohedral functionalization with Surfactants
- D) noncovalent exohedral functionalization with polymers
- E) endohedral functionalization with C_{60}

Interconnect

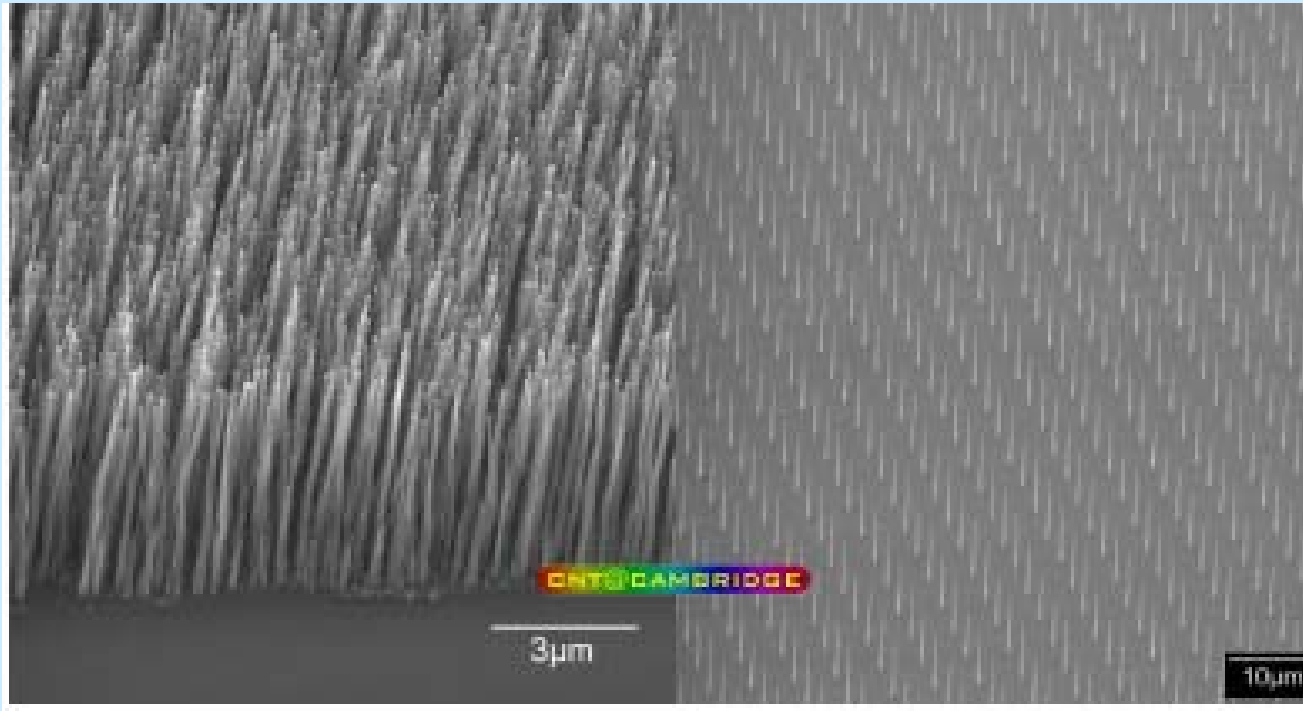


Nanomanipulator



Chemical Sensor

Assembly of CNTs



CNT applications:
Ultra-hard Composites
Nanopipettes
Field Emission Transistor
Nanomanipulator

Carbon Nanotubes

Difficult to obtain in pure form (SWNT, MWNT, C_x, soot etc.)

As-synthesized CNTs are a mixture of conducting, semiconducting and insulating ones

Not stable under oxidizing conditions

Little manufacturing control over tube diameter

Nanowires

Good transport properties – Single crystalline nature

Mechanically robust – Defect free

Flexibility in composition

Doping possible to create p- and n-type nanowires

Nanowires-based FETs and basic logic circuits demonstrated in the laboratory.

Techniques for mass manufacture

Transport in Nanowires

Conductance Quantization:
The Landauer equation

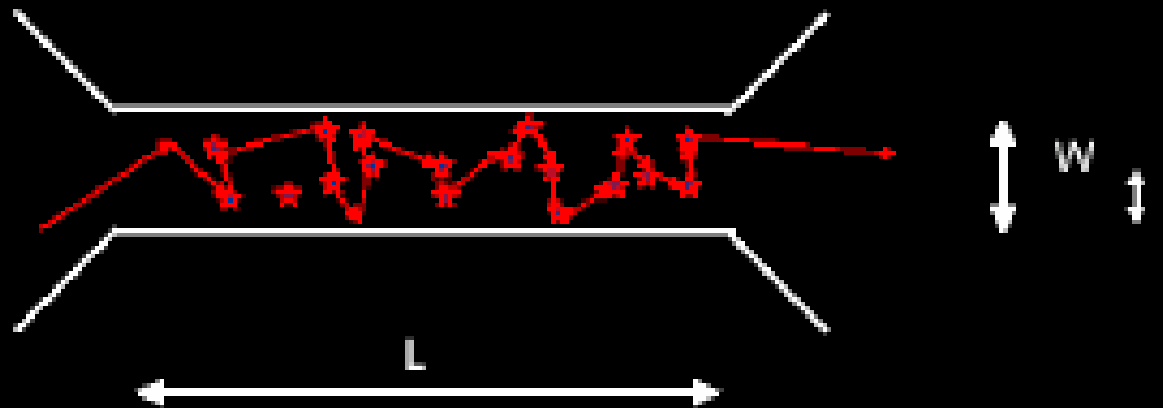
$$G = (2e^2/h)N, N = \text{no. of conduction channels}$$

When NW diameter is smaller than the
Fermi wavelength, conductance
changes in steps of $2e^2/h$

Ballistic vs. diffusive transport

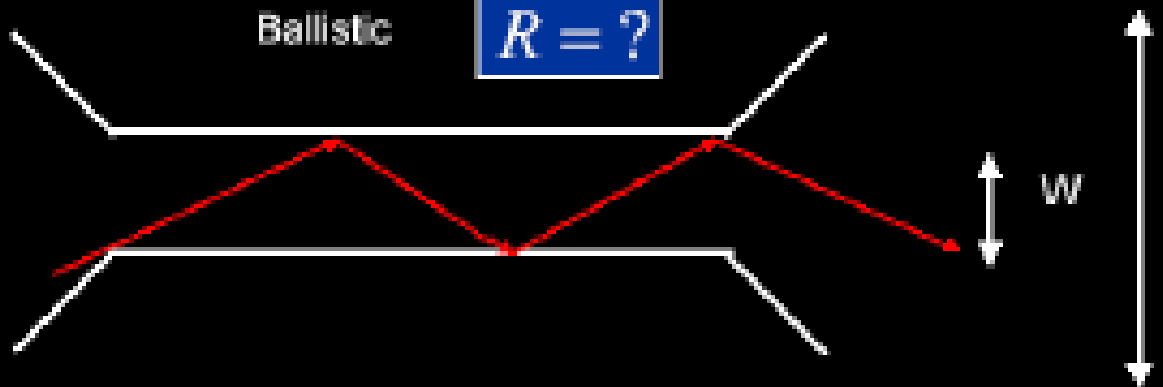
Diffusive

$$R = \frac{L}{W^2} \rho$$



Ballistic

$$R = ?$$



Synthetic Routes to Nanowires

Epitaxial growth

Catalytic VLS growth

Catalytic base growth

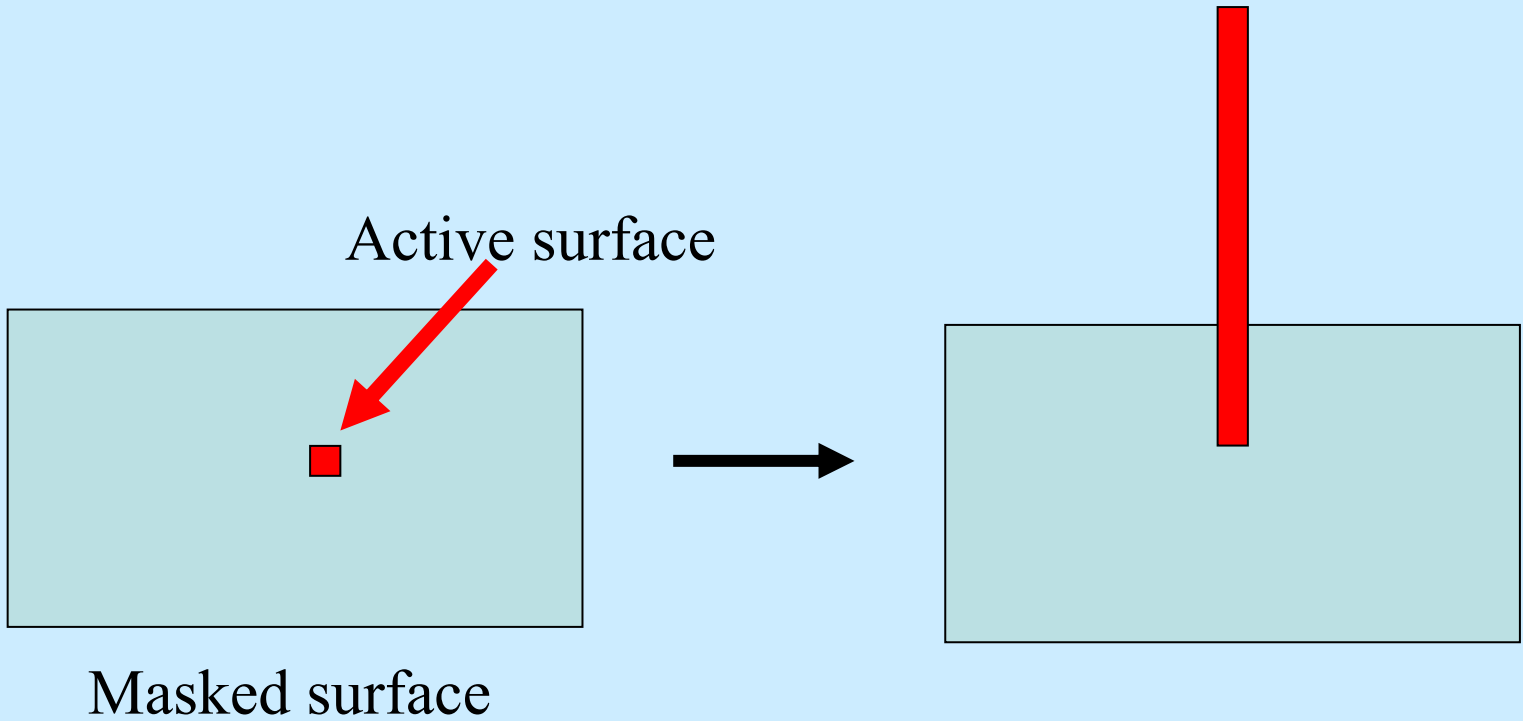
Defect nucleation

Templated growth

Arrested growth

Assembly of nanoparticles

Epitaxial growth



Vapor-Liquid-Solid (VLS) Growth

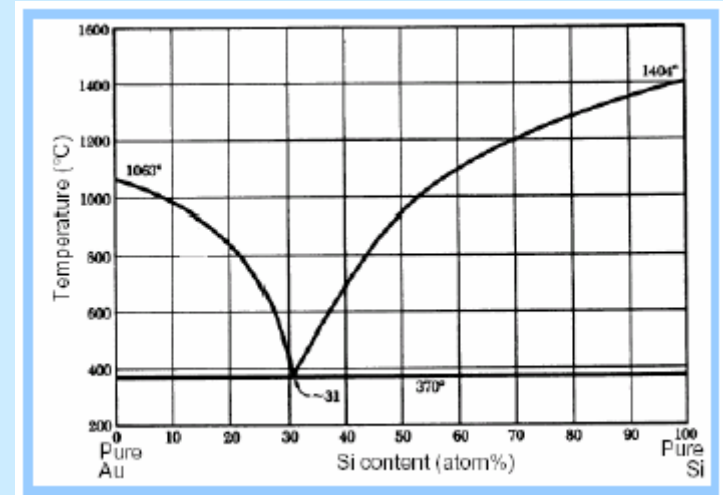
Start with a metal catalyst

Form a liquid droplet of a metallic eutectic when heated

Gaseous precursor feedstock is absorbed

The droplet becomes supersaturated

Excess material is precipitated out to form solid NWs beneath the droplet



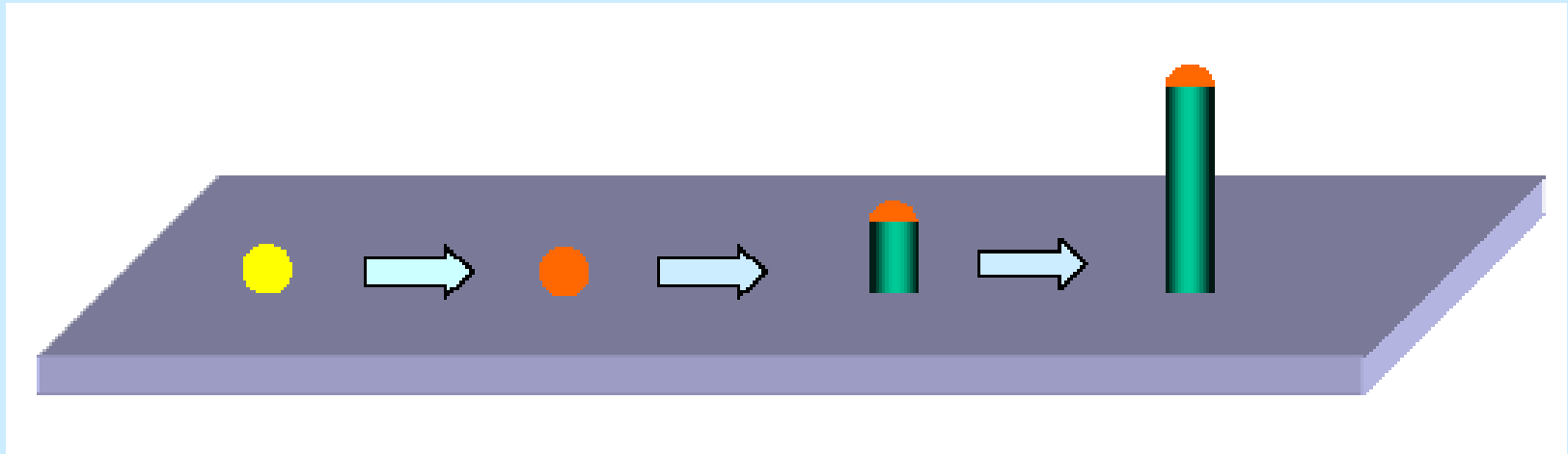
Vapor-Liquid-Solid (VLS) Growth

Au Particles

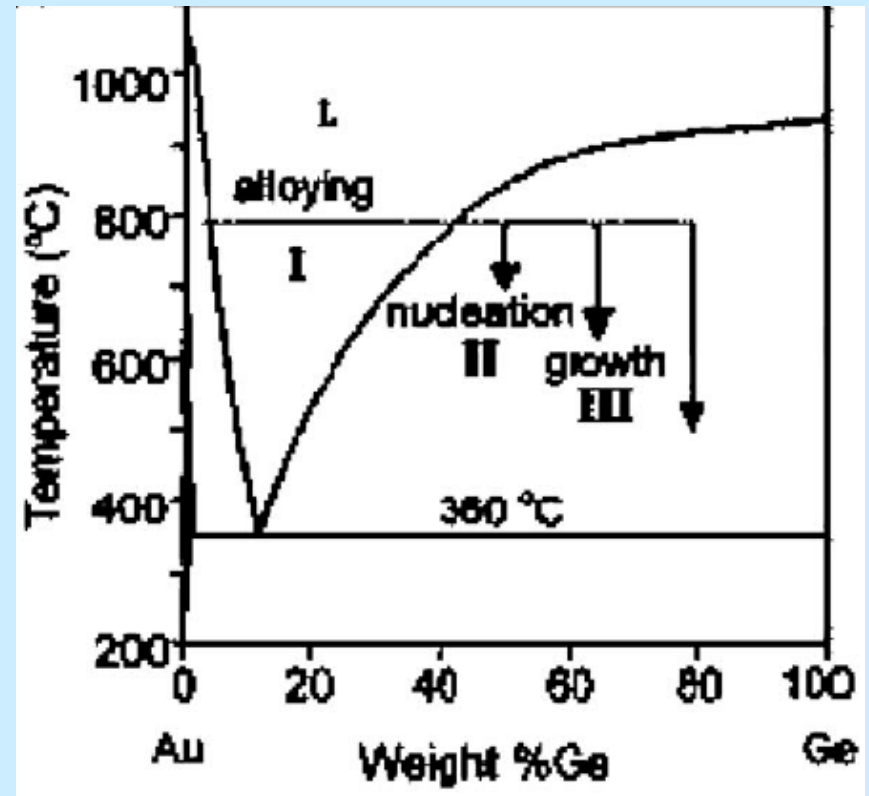
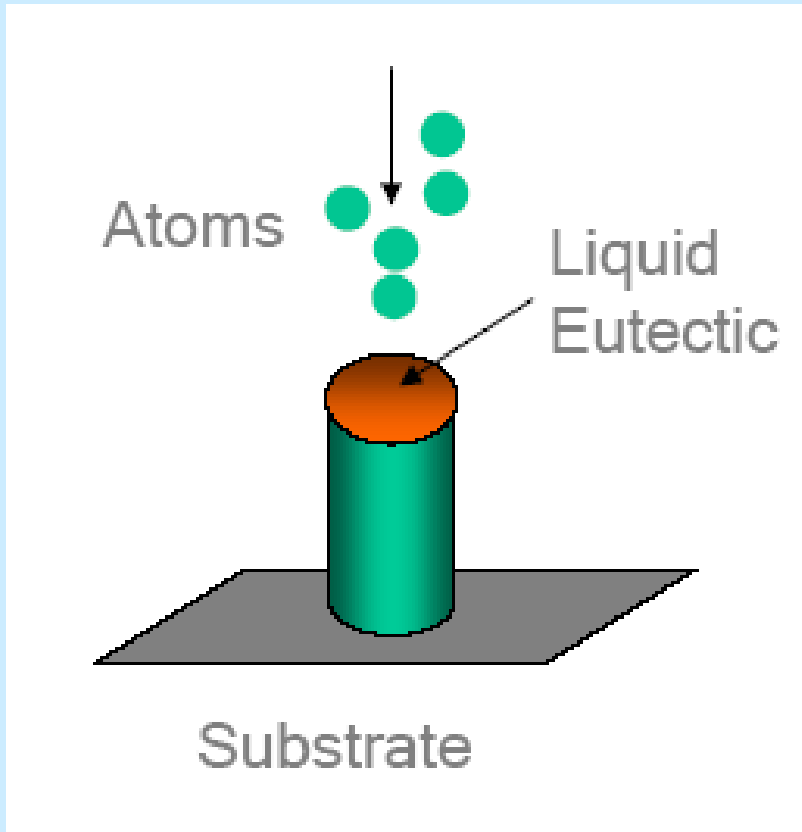
Alloy Liquid

Nucleation of NWs

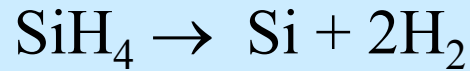
NW Growth



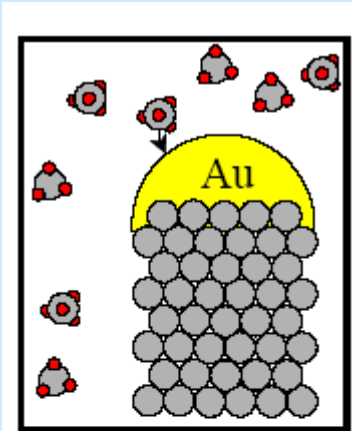
Vapor-Liquid-Solid (VLS) Growth



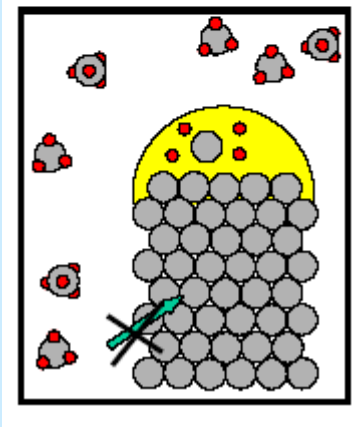
Si Nanowire Growth



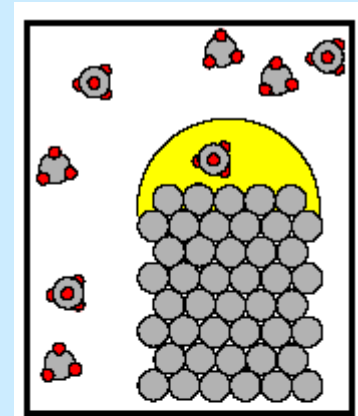
Mass transport
in the gas phase



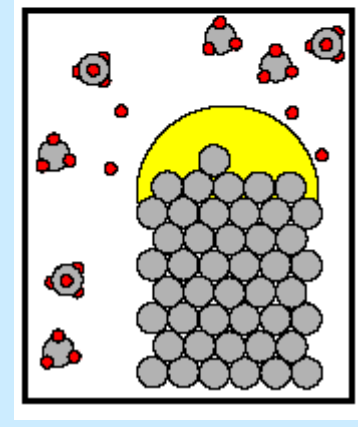
Chemical
reaction at the
V-L interface



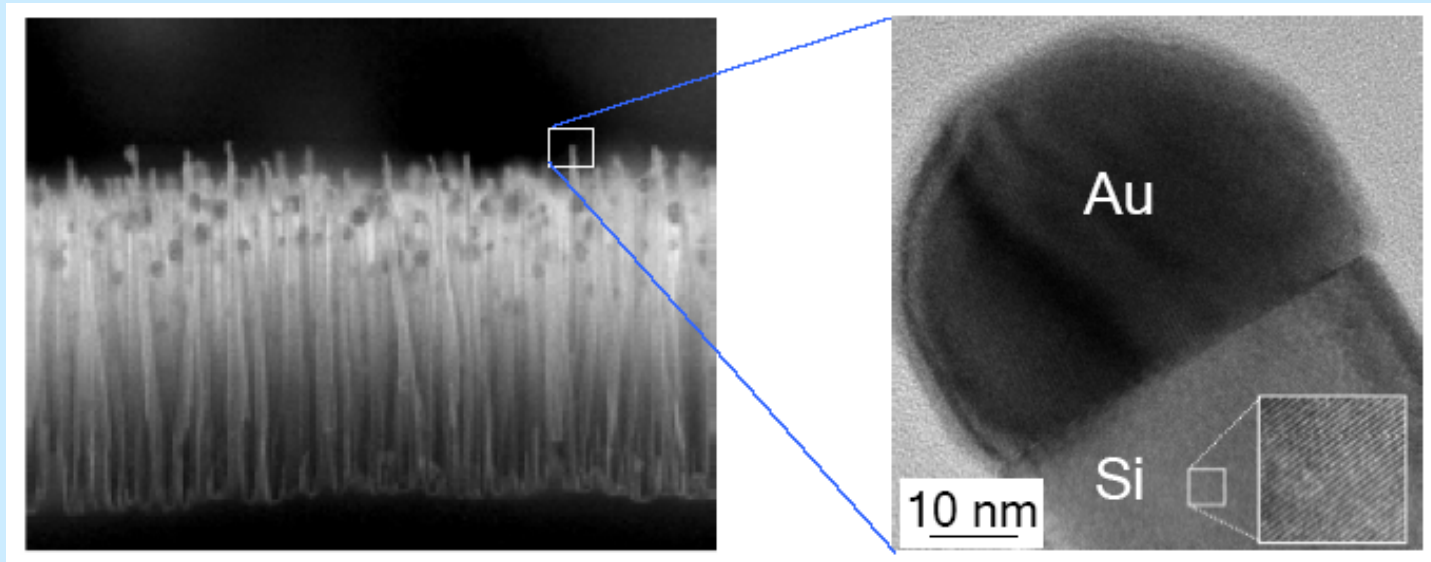
Diffusion in
molten catalyst



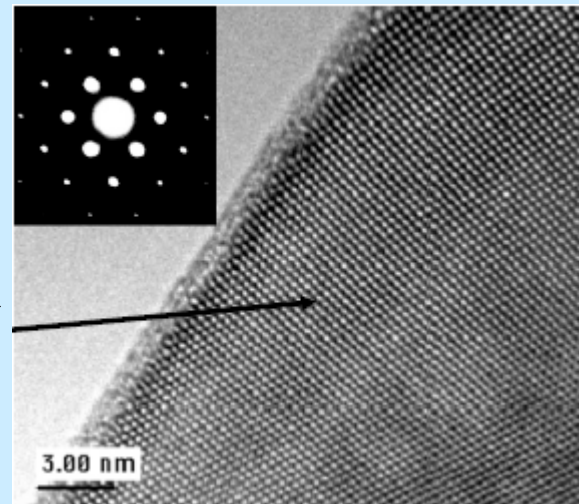
Incorporation of
material in the
crystal lattice



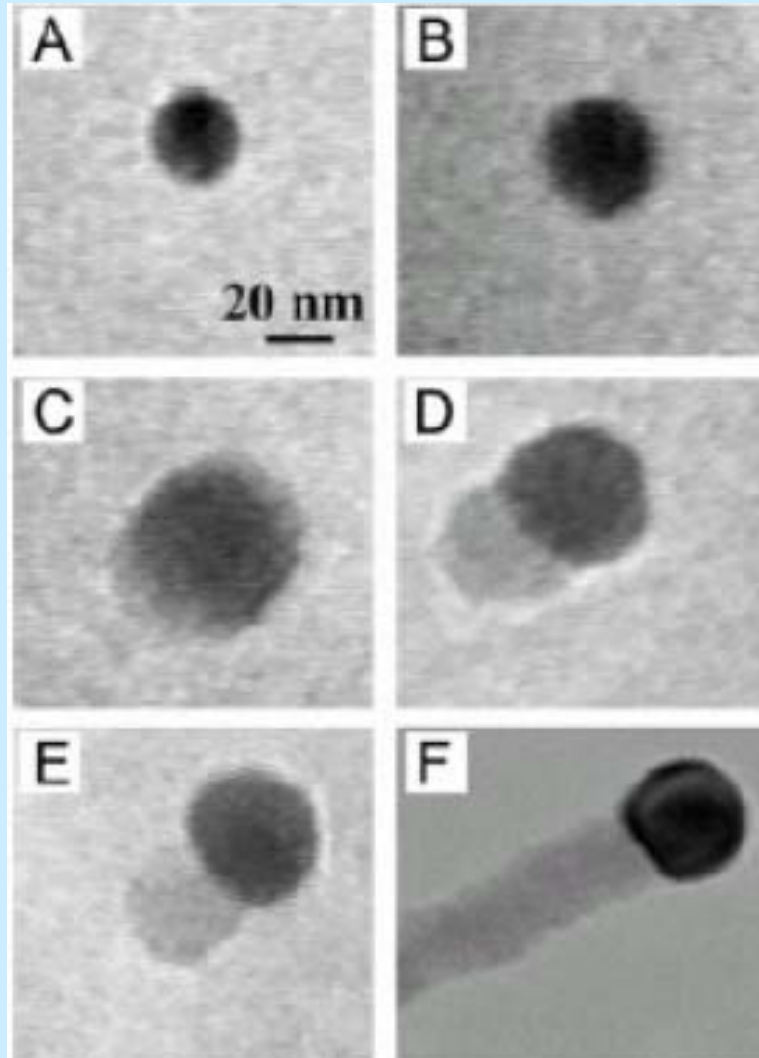
Si Nanowires



Defect-free Si NW

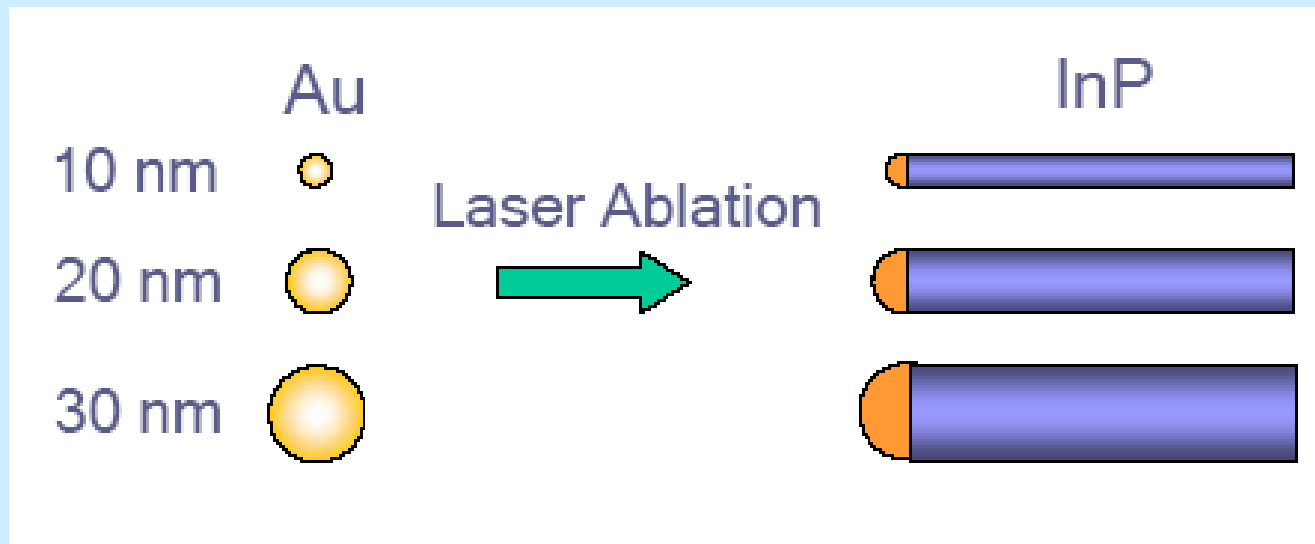


In situ TEM images recorded during the VLS process

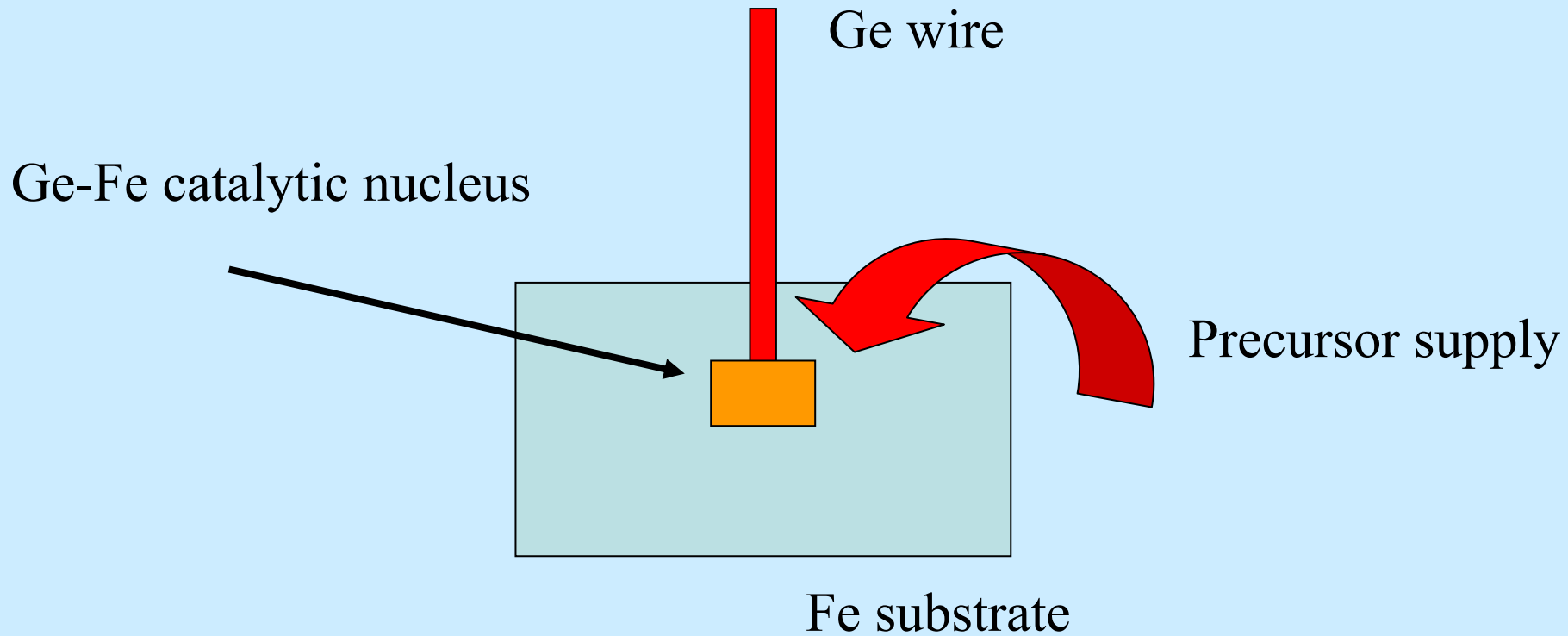


Size Control

Metal particle acts as a soft template to control the diameter of the nanowire

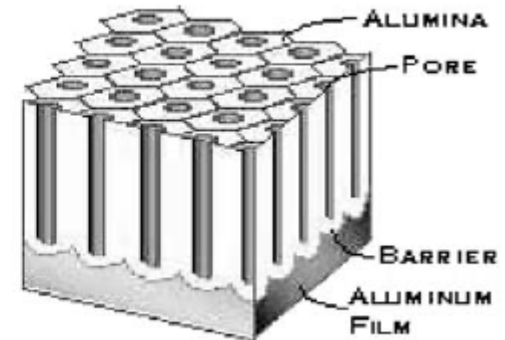
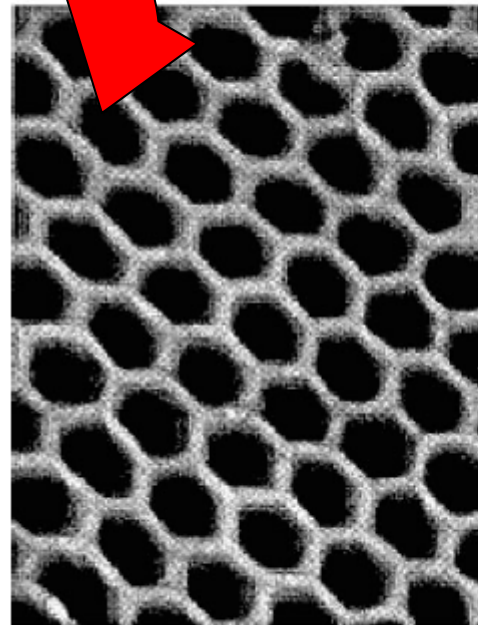
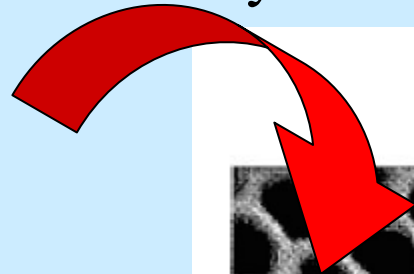


Catalytic base growth

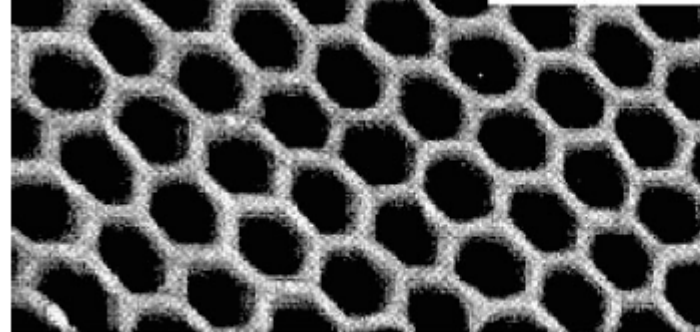


Templated growth

1. Pores filled with material by CVD



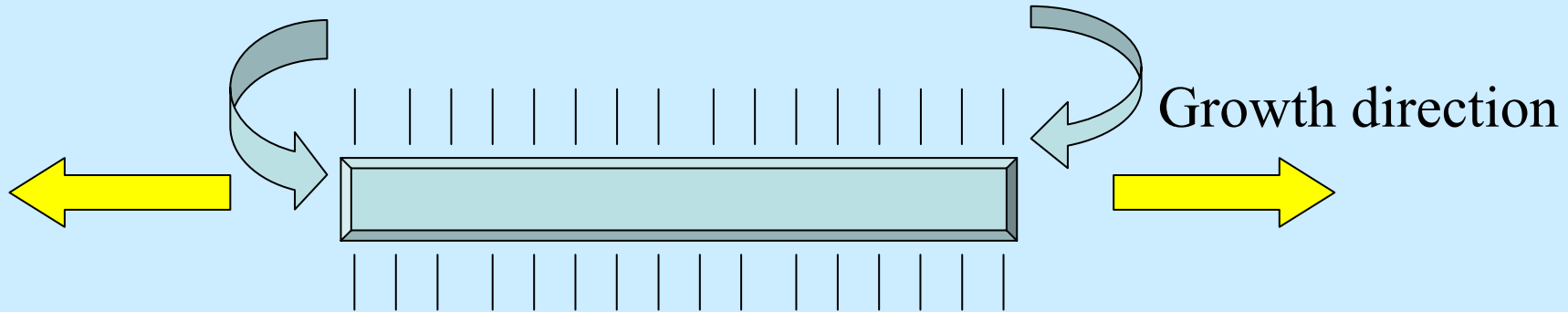
- 2. Alumina matrix dissolved
- 3. Wires separated



200 nm

Arrested growth

Precursor supply

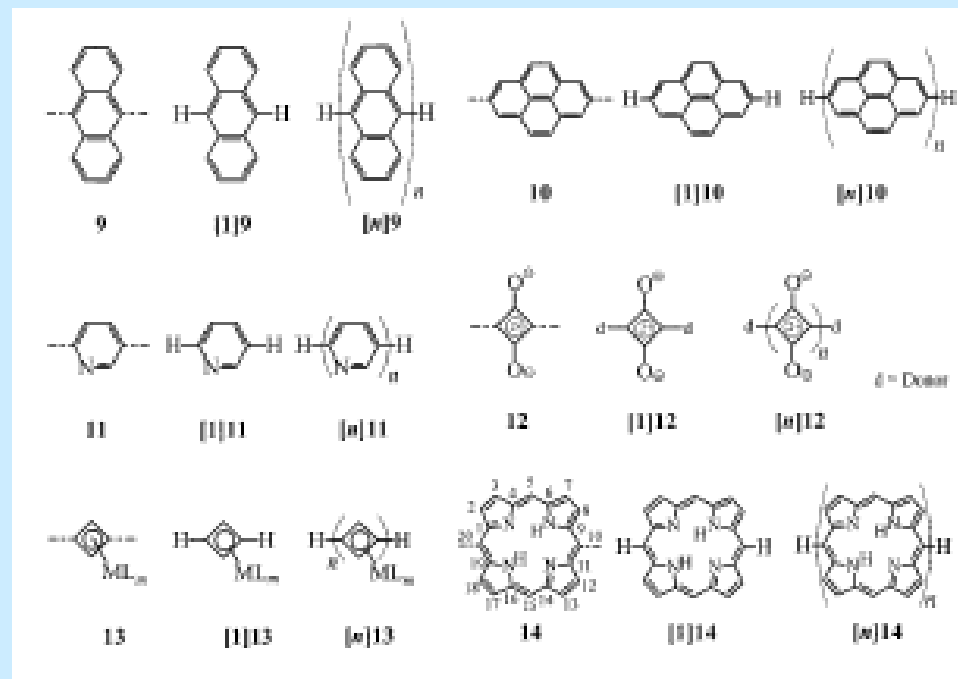
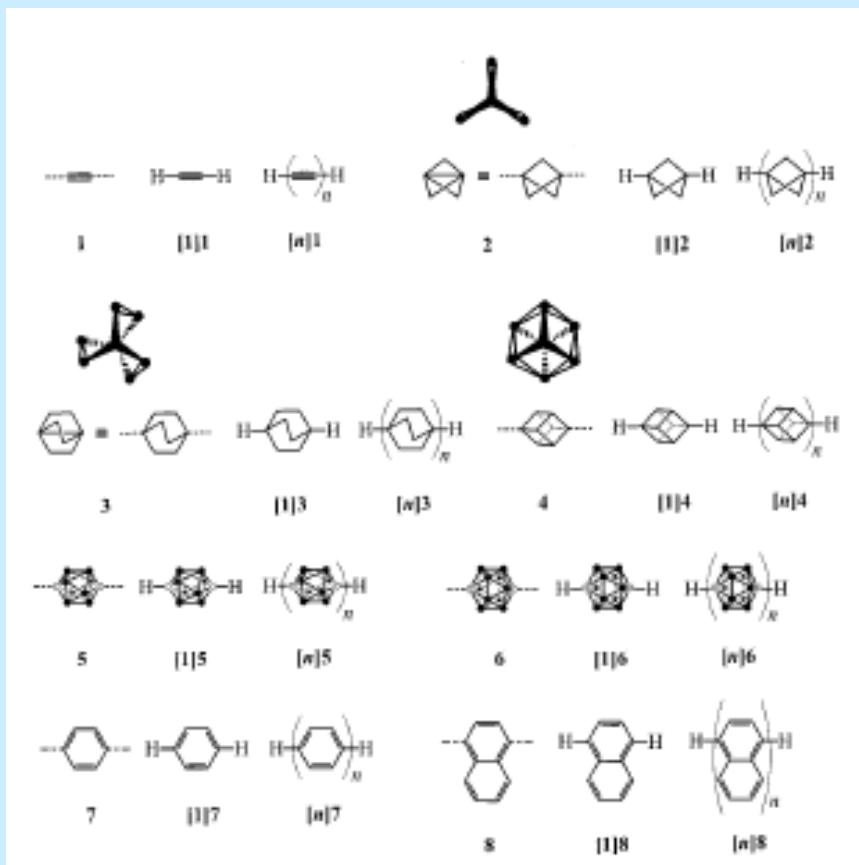


Selective binding of a compound to certain crystal faces

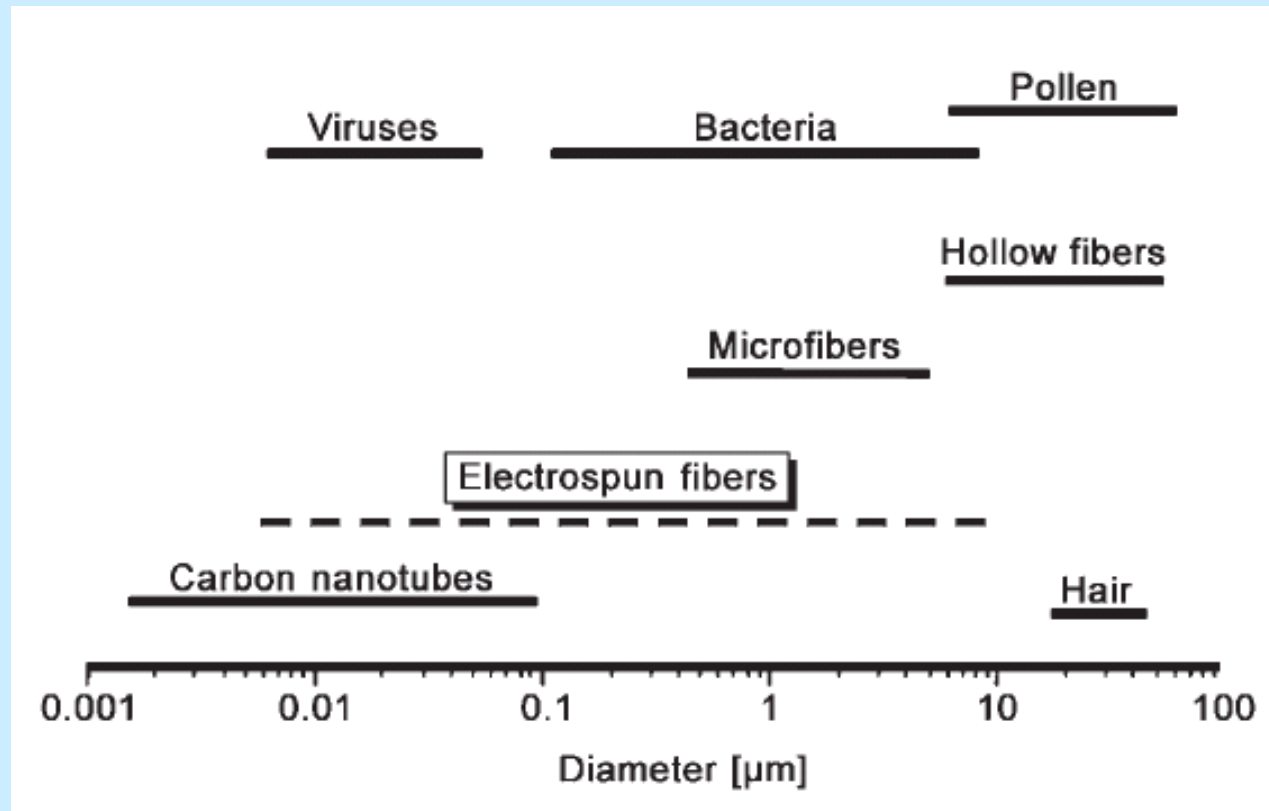
CdTe, TOPO blocks (111)

Alivistos

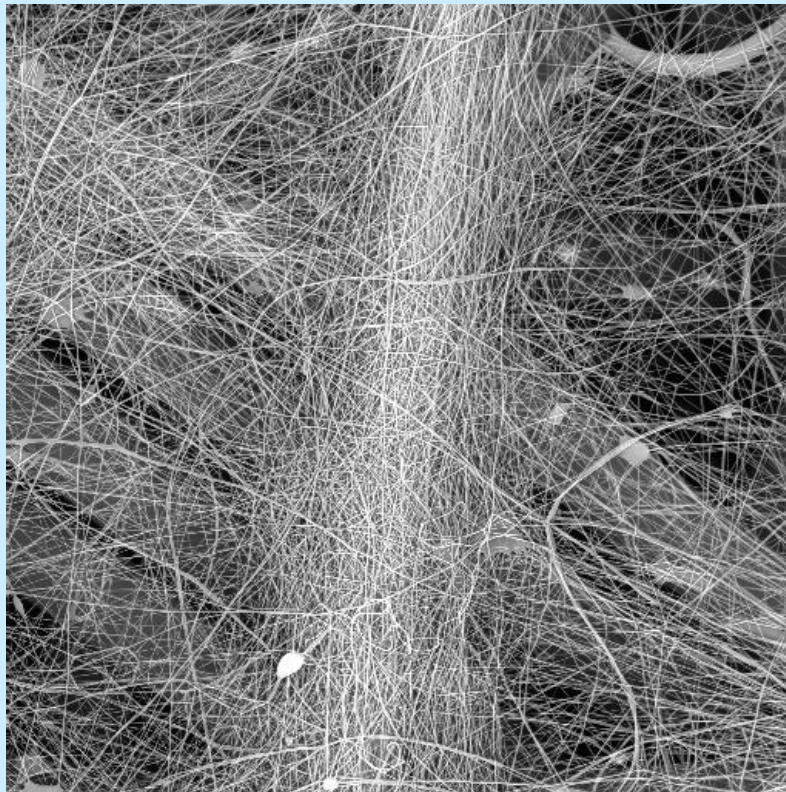
Molecular rods



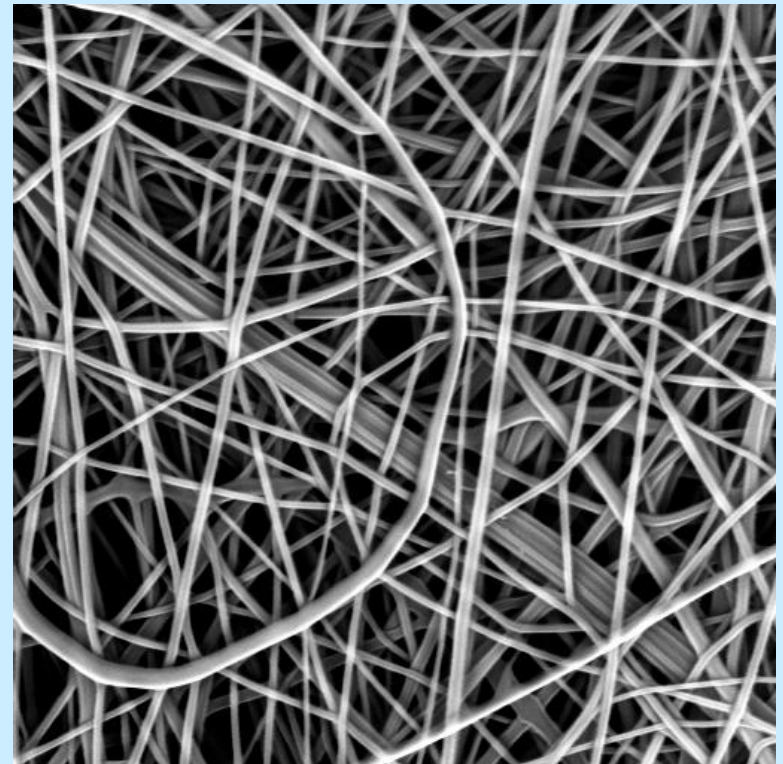
Fibers



Electrospinning

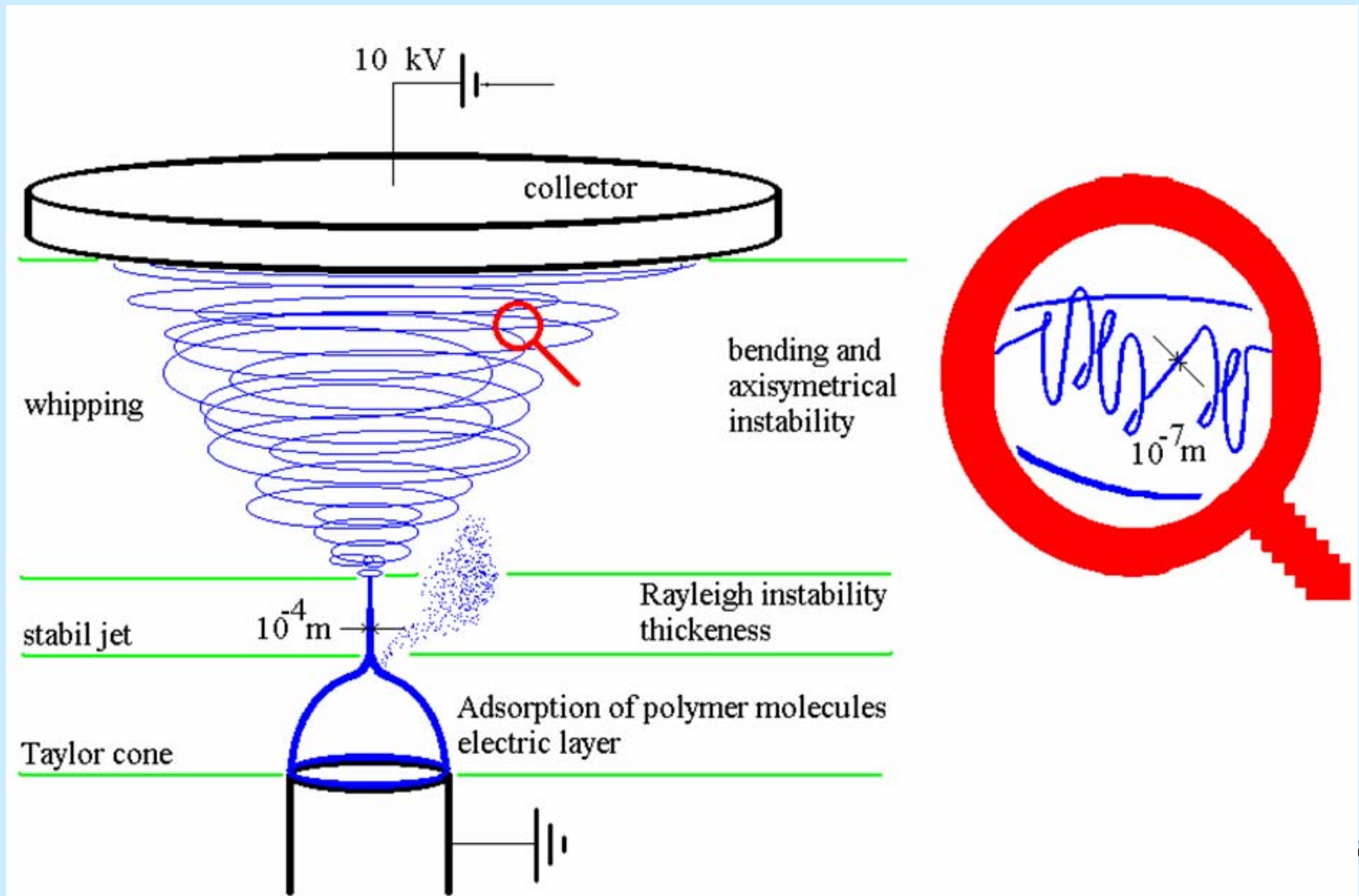


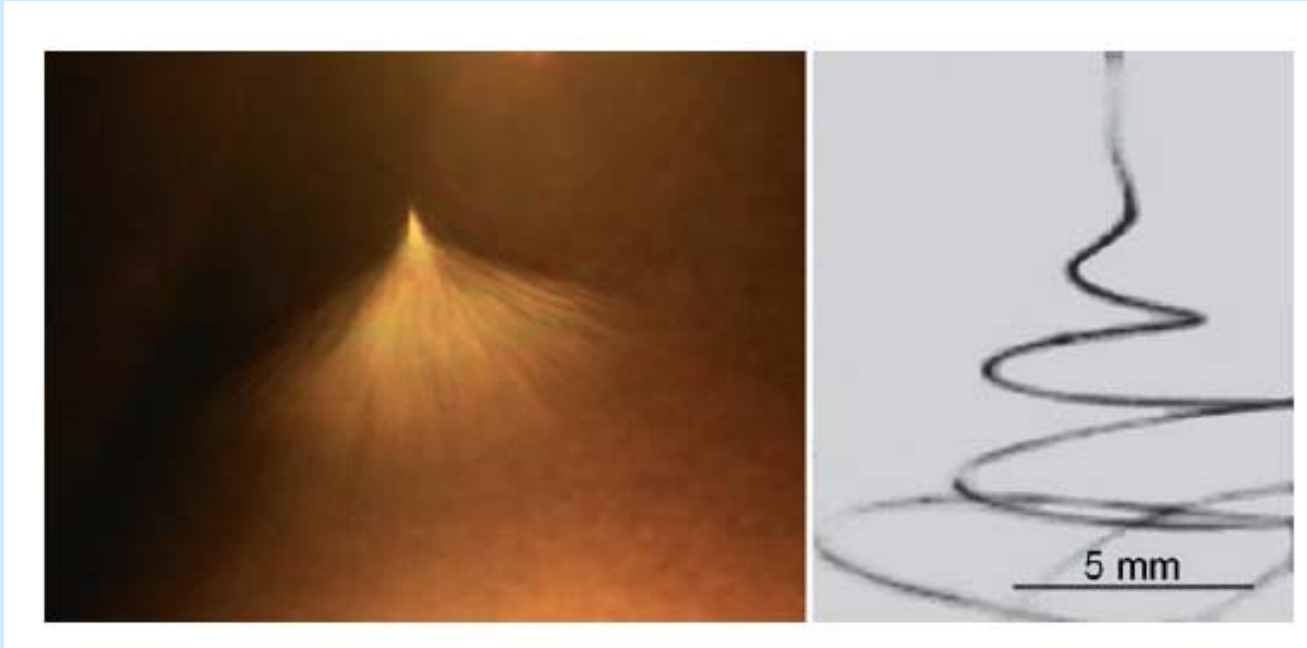
SEM MAG: 1.00 kx DET: BE Detector 50 um Vega ©Tescan
HV: 30.0 kV DATE: 03/10/08 TU Liberec
VAC: HiVac Device: TS5130



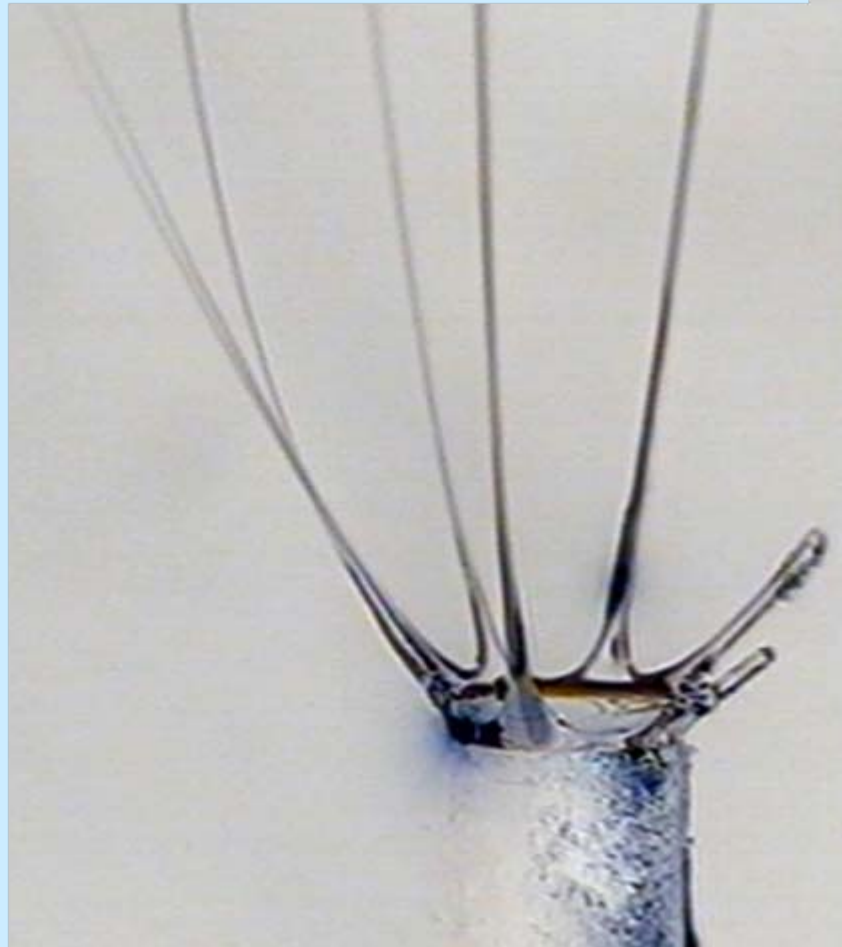
SEM MAG: 10.00 kx DET: BE Detector 5 um Vega ©Tescan
HV: 30.0 kV DATE: 03/10/08 TU Liberec
VAC: HiVac Device: TS5130

Electrospinning

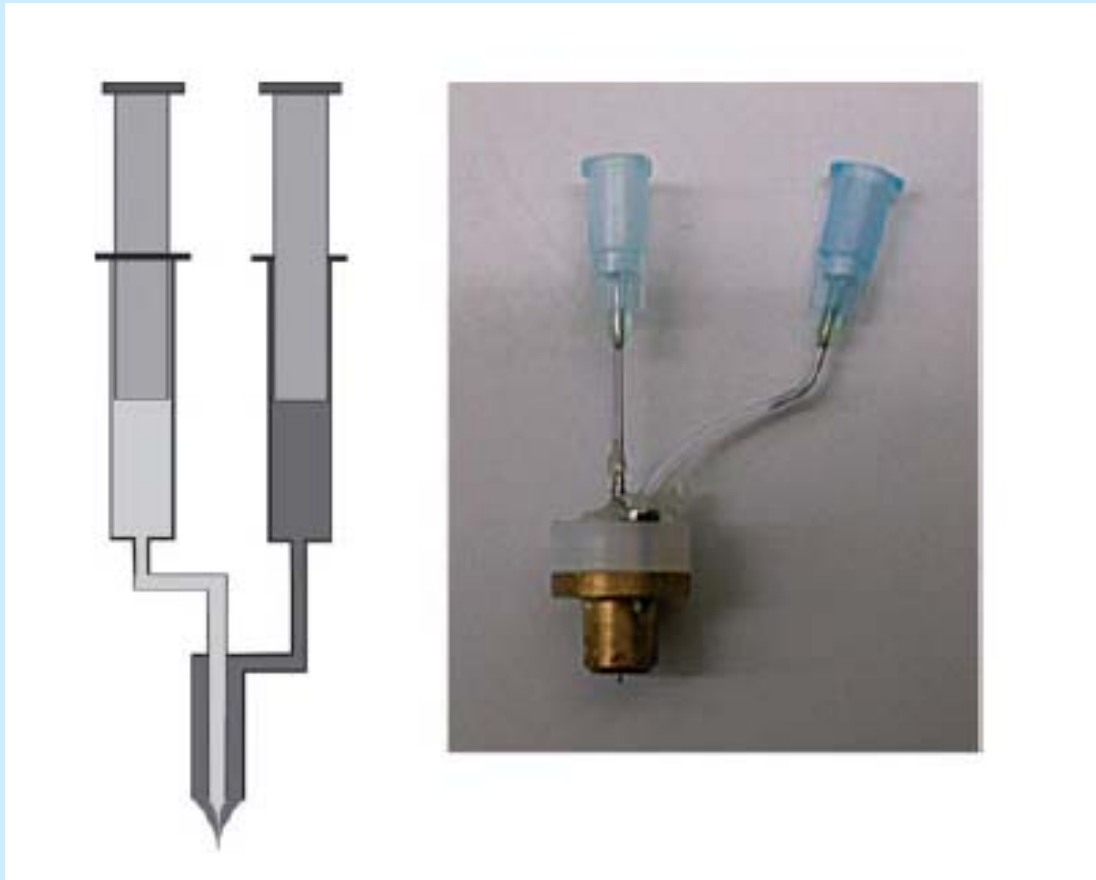




Left: Photograph of a jet of PEO solution during electrospinning.
Right: High-speed photograph of jet instabilities.



Coaxial electrospinning



Multijet electrospinning

